



S/N 10/057,225

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PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Leonard Forbes et al.

Examiner: Michael Trinh

Serial No.: 10/057,225

Group Art Unit: 2822

Filed: January 25, 2002

Docket No.: 303.506US4

Title: METHOD OF FABRICATING A TRANSISTOR ON A SUBSTRATE TO  
OPERATE AS A FULLY DEPLETED STRUCTURE

**AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111**

MS Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

This responds to the Office Action mailed on July 29, 2004. Please amend the above-identified patent application as follows.

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